



2DD2656

LOW V_{CE(SAT)} NPN SURFACE MOUNT TRANSISTOR

Features

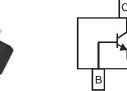
- Epitaxial Planar Die Construction
- Low Collector-Emitter Saturation Voltage
- Ideal for Low Power Amplification and Switching
- Complementary PNP Type Available (2DB1694)
- Ultra-Small Surface Mount Package
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green Device" (Note 2)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe.
 Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 3

Device Schematic

- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)





Top View

Maximum Ratings @ $T_A = 25$ °C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current - Continuous	Ic	1	Α
Peak Pulse Collector Current	I _{CM}	2	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T _A = 25°C	P _D	300	mW
Thermal Resistance, Junction to Ambient (Note 3) @ T _A = 25°C	$R_{ hetaJA}$	417	°C/W
Power Dissipation (Note 4) @ T _A = 25°C	P _D	500	mW
Thermal Resistance, Junction to Ambient (Note 4) @ T _A = 25°C	$R_{ hetaJA}$	250	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	30	_		V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 5)	V _{(BR)CEO}	30	_	_	V	$I_C = 1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6	_	_	V	$I_E = 10\mu A, I_C = 0$
Collector Cut-Off Current	I _{CBO}	_	_	0.1	μΑ	$V_{CB} = 15V, I_{E} = 0$
Emitter Cut-Off Current			_	0.1	μΑ	$V_{EB} = 6V, I_{C} = 0$
ON CHARACTERISTICS (Note 5)	•					•
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		100	350	mV	$I_C = 500 \text{mA}, I_B = 25 \text{mA}$
DC Current Gain		270	_	680		$V_{CE} = 2V, I_{C} = 100mA$
SMALL SIGNAL CHARACTERISTICS	SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	I	5		pF	$V_{CB} = 10V, I_E = 0,$ f = 1MHz
Current Gain-Bandwidth Product	f _T	_	270	_	MHz	V _{CE} = 2V, I _C = 100mA, f = 100MHz

Notes:

- 1. No purposefully added lead.
- 2. Diode's Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Device mounted on FR-4 PCB with minimum recommended pad layout.
- Device mounted on FR-4 PCB with 1 inch² copper pad layout.
- Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.



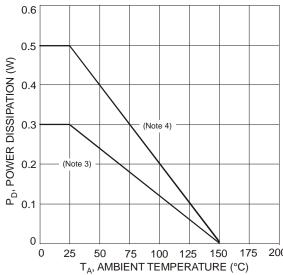


Fig. 1 Power Dissipation vs. Ambient Temperature

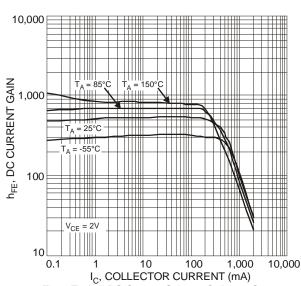
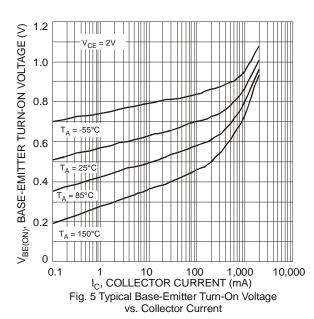
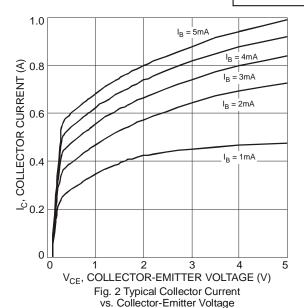


Fig. 3 Typical DC Current Gain vs. Collector Current





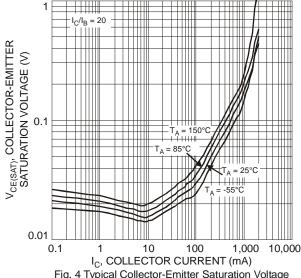


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

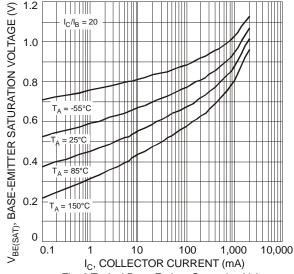
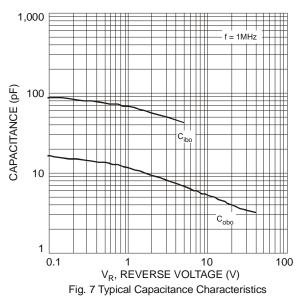


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current



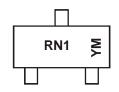


Ordering Information (Note 6)

Part Number	Case	Packaging
2DD2656-7	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

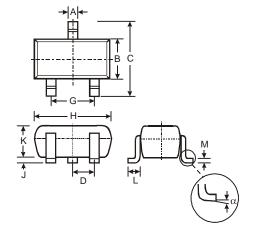


RN1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: V = 2008) M = Month (ex: 9 = September)

Date Code Key

Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	Х		Υ	Z		Α	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

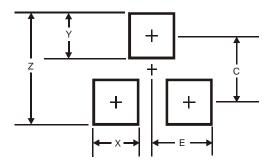
Package Outline Dimensions



SOT-323						
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
В	1.15	1.35	1.30			
С	2.00	2.20	2.10			
D	-	-	0.65			
G	1.20	1.40	1.30			
Ι	1.80	2.20	2.15			
7	0.0	0.10	0.05			
K	0.90	1.00	1.00			
┙	0.25	0.40	0.30			
М	0.10	0.18	0.11			
α	0°	8°	-			
All	All Dimensions in mm					



Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Υ	0.9
С	1.9
E	1.0

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: 2DD2656-7